Spontaneous antiferromagnetic long-range order in the two-dimensional hybrid model of localized Ising spins and itinerant electrons

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(Received 24 August 2009; published 16 November 2009)

The generalized decoration-iteration transformation is adopted to treat exactly a hybrid model of doubly decorated two-dimensional lattices, which have localized Ising spins at their nodal lattice sites and itinerant electrons delocalized over pairs of decorating sites. Under the assumption of a half filling of each couple of the decorating sites, the investigated model system exhibits a remarkable spontaneous antiferromagnetic long-range order with an obvious quantum reduction in the staggered magnetization. It is shown that the critical temperature of the spontaneously long-range ordered quantum antiferromagnet displays an outstanding non-monotonic dependence on a ratio between the kinetic term and the Ising-type exchange interaction.

DOI: 10.1103/PhysRevB.80.174410

PACS number(s): 05.50.+q, 05.70.Jk, 64.60.Cn, 64.60.De

I. INTRODUCTION

Exactly solvable lattice-statistical models are of appreciable scientific interest as they bring a valuable insight into diverse aspects of quantum, cooperative, and critical phenomena.¹⁻⁸ It should be mentioned, however, that sophisticated mathematical methods must be usually employed when searching for an exact treatment of even relatively simple interacting many-body systems while an exact treatment of more realistic or more complex models is often quite unfeasible or is accompanied with a substantial increase in computational difficulties. From this point of view, the exact mapping technique based on generalized algebraic transformations $^{9-11}$ belongs to the simplest mathematical methods, which allows to obtain the exact solution of more complicated model from a precise mapping relationship with a simpler exactly solved model. Following Fisher's ideas,⁹ an arbitrary statistical-mechanical system (even of quantum nature) that merely interacts with either two or three outer Ising spins may be, in principle, replaced by the effective interactions between the outer Ising spins through appropriately chosen decoration-iteration¹² or star-triangle¹³ mapping transformations. Even although the concept based on the generalized algebraic transformations has been worked out by Fisher more than a half century ago,⁹ the algebraic mapping transformations were initially widely used to treat only lattice-statistical models consisting of the Ising spins (see Ref. 10 and references cited therein) before this conceptually simple approach was finally applied to hybrid models composed of the Ising and classical Heisenberg spins,^{14–19} as well as the Ising and quantum Heisenberg spins.²⁰⁻²⁷

Another interesting application of the algebraic mapping transformations has recently been suggested by Pereira *et al.*^{28,29} when applying the generalized decoration-iteration transformation to an intriguing diamond-chain model of interacting spin-electron system. In this diamond-chain model, the nodal lattice sites are occupied by the localized Ising

spins and the mobile electrons can freely move on a couple of interstitial decorating sites symmetrically placed in between two localized Ising spins. The main aim of this work is to treat exactly an analogous two-dimensional (2D) hybrid model defined on doubly decorated planar lattices, which should provide a deeper insight into how itinerant character of the mobile electrons will influence phase transitions and critical phenomena of this interacting spin-electron system.

The outline of this paper is as follows. In Sec. II, we first provide a rather detailed description of the model under investigation together with the most crucial steps of the exact mapping method, which enables us to obtain exact closedform expressions for the critical temperature, order parameter, and other relevant thermodynamic quantities. The most interesting results for the ground state, the finite-temperature phase diagram, and thermodynamics are presented and detailed discussed in Sec. III. Finally, the summary of the most important scientific achievements is mentioned with several concluding remarks in Sec. IV.

II. MODEL AND METHOD

Let us consider a hybrid lattice-statistical model of interacting spin-electron system on doubly decorated 2D lattices, which have one localized Ising spin at each nodal lattice site and two delocalized mobile electrons at each couple of decorating sites. The magnetic structure of the model under investigation is schematically depicted in Fig. 1 on the particular example of the doubly decorated square lattice.

For further convenience, the total Hamiltonian can be defined as a sum over bond Hamiltonians $\hat{\mathcal{H}} = \Sigma_k \hat{\mathcal{H}}_k$, where each bond Hamiltonian $\hat{\mathcal{H}}_k$ involves all the interaction terms of two itinerant electrons from the *k*th bond of the doubly decorated 2D lattice

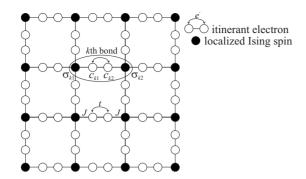


FIG. 1. A part of the doubly decorated square lattice, which has one localized Ising spin at each nodal lattice site (full circle) and two mobile electrons at each couple of decorating sites (empty circles). The ellipse demarcates the localized Ising spins and itinerant electrons described through the *k*th bond Hamiltonian (1).

$$\begin{aligned} \hat{\mathcal{H}}_{k} &= -t(c_{k1,\uparrow}^{\dagger}c_{k2,\uparrow} + c_{k1,\downarrow}^{\dagger}c_{k2,\downarrow} + c_{k2,\uparrow}^{\dagger}c_{k1,\uparrow} + c_{k2,\downarrow}^{\dagger}c_{k1,\downarrow}) \\ &- \frac{J}{2}\hat{\sigma}_{k1}^{z}(c_{k1,\uparrow}^{\dagger}c_{k1,\uparrow} - c_{k1,\downarrow}^{\dagger}c_{k1,\downarrow}) \\ &- \frac{J}{2}\hat{\sigma}_{k2}^{z}(c_{k2,\uparrow}^{\dagger}c_{k2,\uparrow} - c_{k2,\downarrow}^{\dagger}c_{k2,\downarrow}). \end{aligned}$$
(1)

Here, $c_{k\alpha,\gamma}^{\dagger}$ and $c_{k\alpha,\gamma}$ ($\alpha=1,2$ and $\gamma=\uparrow,\downarrow$) denote usual creation and annihilation fermionic operators and $\hat{\sigma}_{k\alpha}^{z}$ is the standard spin-1/2 operator with the eigenvalues $\sigma_{k\alpha}^{z}=\pm 1/2$. The hopping parameter *t* takes into account kinetic energy of

the mobile electrons and the exchange integral J describes the Ising-type interaction between the itinerant electrons and their nearest Ising neighbors.

A crucial step of our approach lies in the calculation of the partition function. Owing to a validity of the commutation relation between different bond Hamiltonians $[\hat{\mathcal{H}}_i, \hat{\mathcal{H}}_j]$ =0, the total partition function \mathcal{Z} can be partially factorized into a product of the bond partition functions \mathcal{Z}_k

$$\mathcal{Z} = \sum_{\{\sigma_i\}} \prod_{k=1}^{Nq/2} \operatorname{Tr}_k \exp(-\beta \hat{\mathcal{H}}_k) = \sum_{\{\sigma_i\}} \prod_{k=1}^{Nq/2} \mathcal{Z}_k,$$
(2)

where $\beta = 1/(k_{\rm B}T)$, $k_{\rm B}$ is Boltzmann's constant, *T* is the absolute temperature, *N* is the total number of the Ising spins (i.e., the nodal lattice sites), and *q* is their coordination number (i.e., the number of nearest-neighbor decorating sites). Next, the symbol $\Sigma_{\{\sigma_i\}}$ denotes a summation over all possible spin configurations of the localized Ising spins and the symbol Tr_k stands for a trace over degrees of freedom of two mobile electrons from the *k*th couple of decorating sites. An explicit form of the bond partition function \mathcal{Z}_k can be subsequently acquired by a direct diagonalization of the bond Hamiltonian (1). On assumption that exactly two electrons are confined at each couple of the decorating sites, the matrix representation of the bond Hamiltonian $\hat{\mathcal{H}}_k$ in the orthonormal basis of states $|\psi_i\rangle \in \{c_{k1,\uparrow}^{\dagger}c_{k2,\uparrow}^{\dagger}|0\rangle, c_{k1,\downarrow}^{\dagger}c_{k2,\uparrow}^{\dagger}|0\rangle, c_{k1,\uparrow}^{\dagger}c_{k1,\downarrow}^{\dagger}|0\rangle, c_{k1,\uparrow}^{\dagger}c_{k2,\downarrow}^{\dagger}|0\rangle$ labels the empty state) reads

$$\langle \psi_j | \hat{\mathcal{H}}_k | \psi_i \rangle = \begin{pmatrix} -h_{k1} - h_{k2} & 0 & 0 & 0 & 0 & 0 \\ 0 & h_{k1} + h_{k2} & 0 & 0 & 0 & 0 \\ 0 & 0 & -h_{k1} + h_{k2} & 0 & -t & -t \\ 0 & 0 & 0 & h_{k1} - h_{k2} & t & t \\ 0 & 0 & -t & t & 0 & 0 \\ 0 & 0 & -t & t & 0 & 0 \end{pmatrix},$$
(3)

where we have defined two new parameters $h_{k1}=J\sigma_{k1}^z/2$ and $h_{k2}=J\sigma_{k2}^z/2$ that include the Ising-type interaction between the mobile electrons and their nearest-neighbor localized Ising spins. It is noteworthy that the parameters h_{k1} and h_{k2} can alternatively be viewed also as generally nonuniform effective field, which is produced by the localized Ising spins on the itinerant electrons situated at the nearest-neighbor decorating sites. The straightforward diagonalization of the Hamiltonian matrix [Eq. (3)] yields six eigenenergies

$$E_{k1,k2} = \pm (h_{k1} + h_{k2}), \quad E_{k3,k4} = 0,$$

$$E_{k5,k6} = \pm \sqrt{(h_{k1} - h_{k2})^2 + 4t^2}, \quad (4)$$

which can be further used for the relevant calculation of the bond partition function Z_k . After tracing out the degrees of

freedom of the itinerant electrons, the bond partition function \mathcal{Z}_k merely depends on spin states of two localized Ising spins and, besides, its explicit form immediately implies a possibility of performing the generalized decoration-iteration transformation^{9–11}

$$\mathcal{Z}_{k} = \sum_{i=1}^{6} \exp(-\beta E_{ki}) = 2 + 2 \cosh\left[\frac{\beta J}{2}(\sigma_{k1}^{z} + \sigma_{k2}^{z})\right] + 2 \cosh\left[\frac{\beta}{2}\sqrt{J^{2}(\sigma_{k1}^{z} - \sigma_{k2}^{z})^{2} + (4t)^{2}}\right] = A \exp(\beta R \sigma_{k1}^{z} \sigma_{k2}^{z}).$$
(5)

The physical meaning of the mapping transformation

[Eq. (5)] is to replace the bond partition function Z_k by the equivalent expression, which would contain the effective pair interaction *R* between the localized Ising spins only. The mapping parameters *A* and *R* are unambiguously given by the "self-consistency" condition of the algebraic transformation [Eq. (5)], which must hold for any combination of spin states of two Ising spins σ_{k1}^z and σ_{k2}^z involved therein. It can be readily proved that the decoration-iteration transformation [Eq. (5)] indeed represents a set of two independent equations, which directly determine the mapping parameters *A* and *R*

$$A = (V_1 V_2)^{1/2}, \quad \beta R = 2 \ln(V_1 / V_2) \tag{6}$$

that are for the sake of brevity expressed in terms of the newly defined functions V_1 and V_2

$$V_1 = 2 + 2 \cosh(\beta J/2) + 2 \cosh(2\beta t),$$
$$V_2 = 4 + 2 \cosh[\beta \sqrt{J^2 + (4t)^2}/2].$$
(7)

Substituting the algebraic transformation [Eq. (5)] into the factorized form of the partition function (2), which physically corresponds to performing the decoration-iteration mapping at each bond of the doubly decorated 2D lattice, consequently leads to a simple mapping relationship between the partition function Z of the interacting spin-electron system on the doubly decorated 2D lattice and, respectively, the partition function Z_{IM} of the simple spin-1/2 Ising model on the corresponding undecorated lattice with the effective (temperature-dependent) nearest-neighbor interaction *R*

$$\mathcal{Z}(\beta, J, t) = A^{Nq/2} \mathcal{Z}_{IM}(\beta, R).$$
(8)

The mapping relation in Eq. (8) essentially completes our exact calculation of the partition function Z since the partition function of the nearest-neighbor spin-1/2 Ising model has been precisely calculated for several 2D lattices (for reviews see Refs. 10, 30, and 31). For brevity, let us therefore merely quote the respective results for the partition functions of the spin-1/2 Ising model on the square lattice¹³

$$\lim_{N \to \infty} \frac{1}{N} \ln \mathcal{Z}_{IM} = \ln 2 + \frac{1}{4\pi^2} \int_0^{2\pi} \int_0^{2\pi} \ln[\cosh^2(\beta R/2) - \sinh(\beta R/2)(\cos \theta + \cos \phi)] d\theta d\phi \quad (9)$$

and the honeycomb lattice³²

$$\lim_{N \to \infty} \frac{1}{N} \ln \mathcal{Z}_{IM} = \ln 2 + \frac{1}{16\pi^2} \int_0^{2\pi} \int_0^{2\pi} \\ \times \ln[\{1 + \cosh^3(\beta R/2) - \sinh^2(\beta R/2) \\ \times [\cos \theta + \cos \phi + \cos(\theta + \phi)]\}/2] d\theta d\phi.$$
(10)

In what follows, the precise mapping relationship [Eq. (8)] between the partition functions will be used as a starting point for performing a rather comprehensive analysis of the critical behavior, the order parameter, and basic thermodynamic quantities.

A. Critical condition

In order to locate a critical point of the investigated spinelectron system, one may take advantage of the fact that the partition function always becomes nonanalytic at a critical point. It can be easily understood from Eq. (6) to Eq. (8) that the mapping parameter A cannot cause a nonanalytic behavior of the partition function \mathcal{Z} and thus, the investigated spinelectron system becomes critical if and only if the corresponding spin-1/2 Ising model with the effective coupling βR becomes critical as well. Accordingly, the critical points of the investigated spin-electron system can be straightforwardly obtained from a comparison of the effective temperature-dependent coupling βR with the relevant critical point of the corresponding spin-1/2 Ising model on the undecorated lattice. However, the mathematical structure of the mapping parameter R has another important consequences on a critical behavior. More specifically, one may easily prove from Eq. (7) a general validity of the inequality $V_1 < V_2$, which in compliance with the definition in Eq. (6) implies the antiferromagnetic nature of the effective interaction (R < 0) in the spin-1/2 Ising model on the corresponding undecorated lattice. Owing to this fact, the interacting spinelectron system is always mapped on the spin-1/2 Ising model with the antiferromagnetic nearest-neighbor interaction, which has a nonzero critical temperature only on the 2D loose-packed lattices such as square¹³ and honevcomb³²⁻³⁶ lattices. As a matter of fact, it is well-known dictum that the spin-1/2 Ising model with the antiferromagnetic nearestneighbor interaction on close-packed lattices such as triangular^{32,36,37} and kagomé^{12,38} lattices does not exhibit a spontaneous long-range order at any finite temperature and consequently, it does not have any finite-temperature critical point that would correspond to the order-disorder transition.

Bearing all this in mind, we will consider hereafter only the interacting spin-electron system on the doubly decorated 2D loose-packed lattices. It is worthwhile to remark that the critical temperature of the antiferromagnetic spin-1/2 Ising model on the loose-packed lattices is equal to the one of the ferromagnetic model and hence, the critical points for the spin-electron system on the doubly decorated square and honeycomb lattices readily follow from the conditions $\beta_c |R| = 2 \ln(1 + \sqrt{2})$ (Ref. 13) and, respectively, $\beta_c |R| = 2 \ln(2 + \sqrt{3})$ (Ref. 32) where $\beta_c = 1/(k_B T_c)$ and T_c is the

critical temperature.

B. Staggered magnetization

As a direct consequence of the mapping equivalence with the antiferromagnetic spin-1/2 Ising model on the relevant undecorated loose-packed lattice, one should anticipate predominantly antiferromagnetic character of the interacting spin-electron system on the doubly decorated 2D loosepacked lattice as well. Let us therefore calculate the staggered magnetization as the most common order parameter inherent to the antiferromagnetic spin alignment. Using the exact mapping theorems developed by Barry *et al.*,^{39–42} the spontaneous staggered magnetization of the localized Ising spins can easily be calculated from the exact spin identity

$$m_{i} \equiv \frac{1}{2} \langle \hat{\sigma}_{k1}^{z} - \hat{\sigma}_{k2}^{z} \rangle_{t,J} = \frac{1}{2} \langle \hat{\sigma}_{k1}^{z} - \hat{\sigma}_{k2}^{z} \rangle_{R} \equiv m_{\text{IM}}(\beta R), \quad (11)$$

where the symbols $\langle \cdots \rangle_{t,J}$ and $\langle \cdots \rangle_R$ denote standard canonical ensemble average performed within the interacting spinelectron model on the doubly decorated 2D lattice and, respectively, its equivalent spin-1/2 Ising model on the corresponding undecorated 2D lattice.43 The exact spin identity [Eq. (11)] furnishes an accurate proof that the staggered magnetization of the Ising sublattice in the interacting spinelectron model on the doubly decorated 2D lattice directly equals the staggered magnetization of the spin-1/2 Ising model on the corresponding undecorated 2D lattice with the antiferromagnetic nearest-neighbor interaction R < 0. However, the spontaneous staggered magnetization of the antiferromagnetic spin-1/2 Ising model on the loose-packed 2D lattices precisely coincides with the spontaneous magnetization of the ferromagnetic model, i.e., the quantity, which has exactly been determined for several 2D Ising models (see Ref. 44 and references cited therein). In this regard, the staggered magnetization of the antiferromagnetic spin-1/2 Ising model on the square⁴⁵ and honeycomb⁴⁶ lattices for instance read

$$m_{\rm IM} = \frac{1}{2} \left[1 - \frac{16x^4}{(1-x^2)^4} \right]^{1/8}, \quad \text{(square)},$$
$$m_{\rm IM} = \frac{1}{2} \left[1 - \frac{16x^3(1+x^3)}{(1-x)^3(1-x^2)^3} \right]^{1/8}, \quad \text{(honeycomb)},$$
(12)

where $x = \exp(-\beta R/2)$. The above formulas complete our calculation of the staggered magnetization of the localized Ising spins when substituting the exact expression in Eq. (12) with the appropriately chosen effective coupling [Eqs. (6) and (7)] into the exact spin identity [Eq. (11)].

On the other hand, the staggered magnetization of the itinerant electrons delocalized over pairs of decorating sites can be calculated with the aid of the generalized Callen-Suzuki identity^{47–51}

$$\langle f(c_{k\alpha,\gamma}^{\dagger}c_{k\alpha,\gamma})\rangle_{t,J} = \left\langle \frac{\operatorname{Tr}_{k}f(c_{k\alpha,\gamma}^{\dagger}c_{k\alpha,\gamma})\exp(-\beta\hat{\mathcal{H}}_{k})}{\operatorname{Tr}_{k}\exp(-\beta\hat{\mathcal{H}}_{k})}\right\rangle_{t,J},$$
(13)

where $\alpha = 1, 2$, $\gamma = \uparrow, \downarrow$, and *f* is, in principle, an arbitrary function of the creation and annihilation fermionic operators from the *k*th bond Hamiltonian (1). With the help of the exact identity [Eq. (13)], the spontaneous staggered magnetization of the itinerant electrons can be calculated from the expression

$$m_e = \frac{1}{2} \langle (\hat{S}_{k1}^z - \hat{S}_{k2}^z) \rangle_{t,J} = \left\langle \frac{1}{4\beta \mathcal{Z}_k} \left(\frac{\partial \mathcal{Z}_k}{\partial h_{k1}} - \frac{\partial \mathcal{Z}_k}{\partial h_{k2}} \right) \right\rangle_{t,J},$$
(14)

where $\hat{S}_{k\alpha}^{z} = (c_{k\alpha,\uparrow}^{\dagger}c_{k\alpha,\uparrow} - c_{k\alpha,\downarrow}^{\dagger}c_{k\alpha,\downarrow})/2$ marks the *z*th component of the spin operator of the mobile electron. After a straightforward calculation based on the differential operator technique $\exp(a\partial/\partial x + b\partial/\partial y)g(x,y) = g(x+a,y+b)$ (Refs.

52 and 53) and the exact van der Waerden identity $\exp(c\sigma^z) = \cosh(c/2) + 2\sigma^z \sinh(c/2)$, the staggered magnetization of the itinerant electrons can be related to the staggered magnetization of the localized Ising spins through the precise formula

$$m_{e} = m_{i} \frac{J}{\sqrt{J^{2} + (4t)^{2}}} \frac{\sinh\left[\frac{\beta}{2}\sqrt{J^{2} + (4t)^{2}}\right]}{2 + \cosh\left[\frac{\beta}{2}\sqrt{J^{2} + (4t)^{2}}\right]}.$$
 (15)

Since the exact expression for the staggered magnetization of the localized Ising spins is already known from Eq. (11) to Eq. (12), the formula (15) provides the relevant exact result for the staggered magnetization of the itinerant electrons hopping between the decorating sites.

C. Thermodynamics

Before concluding this section, it is worthy of notice that several basic thermodynamic quantities can also be easily derived from the exact mapping equivalence [Eq. (8)] between the partition functions \mathcal{Z} and \mathcal{Z}_{IM} . For instance, the Helmholtz free energy *F*, the internal energy *U*, the entropy *S*, and the specific heat *C*, can directly be computed from the basic relations of thermodynamics and statistical physics such as

$$F = -k_{\rm B}T \ln \mathcal{Z}, \quad U = -\frac{\partial \ln \mathcal{Z}}{\partial \beta}, \quad S = -\frac{\partial F}{\partial T}, \quad C = \frac{\partial U}{\partial T}$$

III. RESULTS AND DISCUSSION

Now, let us proceed to a discussion of the most interesting results obtained for the interacting spin-electron system on the doubly decorated 2D lattices. Before doing this, however, the relations in Eqs. (6) and (7) might serve in evidence that the effective nearest-neighbor interaction R of the spin-1/2 Ising model on the corresponding undecorated lattice is invariant under the transformation $J \rightarrow -J$. A change in the ferromagnetic Ising interaction J > 0 to the antiferromagnetic one J < 0 actually causes only a rather trivial change in the mutual spin orientation of the itinerant electrons and their nearest Ising neighbors. This observation would suggest that the critical temperature as well as other thermodynamic quantities remain unchanged under the sign change $J \rightarrow -J$ and thus, one may further consider the ferromagnetic interaction J > 0 without loss of the generality.

A. Ground state

First, let us take a closer look at the ground-state behavior. It is quite evident that the ground state will correspond to the lowest-energy eigenvalue of the bond Hamiltonian (1), which can be obtained from the eigenenergies [Eq. (4)] by considering four available configurations of the Ising spins σ_{k1} and σ_{k2} explicitly involved therein. It turns out that the lowest-energy eigenstate constitutes a peculiar four-

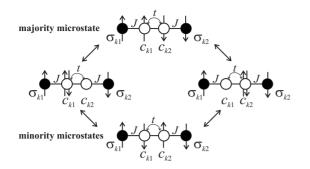


FIG. 2. A schematic representation of the quantum entanglement of two antiferromagnetic and two nonmagnetic ionic states, which occurs in $|AF\rangle$ on account of a virtual hopping process of the mobile electrons.

sublattice quantum antiferromagnet, which can be characterized through the eigenvector

$$|AF\rangle = \prod_{k=1}^{Nq/2} |\uparrow,\downarrow\rangle_{\sigma_{k1},\sigma_{k2}} \left[\frac{1}{2} \left(1 + \frac{J}{\sqrt{J^2 + (4t)^2}} \right) c^{\dagger}_{k1,\uparrow} c^{\dagger}_{k2,\downarrow} - \frac{1}{2} \left(1 - \frac{J}{\sqrt{J^2 + (4t)^2}} \right) c^{\dagger}_{k1,\downarrow} c^{\dagger}_{k2,\uparrow} + \frac{2t}{\sqrt{J^2 + (4t)^2}} (c^{\dagger}_{k1,\uparrow} c^{\dagger}_{k1,\downarrow} + c^{\dagger}_{k2,\uparrow} c^{\dagger}_{k2,\downarrow}) \right] |0\rangle, \quad (16)$$

where the product runs over all bonds of the doubly decorated 2D lattice, the former ket vector determines spin states of the localized Ising spins and the latter one spin states of mobile electrons. Interestingly, one may also find a much simpler goniometric representation of the lowest-energy eigenstate $|AF\rangle$ by introducing the mixing angle ϕ through the definition tan $2\phi=4t/J$, which yields for the particular case with J>0 (Ref. 54)

$$|AF\rangle = \prod_{k=1}^{Nq/2} |\uparrow,\downarrow\rangle_{\sigma_{k1},\sigma_{k2}} [\cos^2 \phi c^{\dagger}_{k1,\uparrow} c^{\dagger}_{k2,\downarrow} - \sin^2 \phi c^{\dagger}_{k1,\downarrow} c^{\dagger}_{k2,\uparrow} + \sin \phi \cos \phi (c^{\dagger}_{k1,\uparrow} c^{\dagger}_{k1,\downarrow} + c^{\dagger}_{k2,\uparrow} c^{\dagger}_{k2,\downarrow})]|0\rangle.$$
(17)

Altogether, the four-sublattice quantum antiferromagnet $|AF\rangle$ can be characterized by a perfect Néel order of the Ising spins situated at the nodal sites of some loose-packed 2D lattice while the mobile electrons delocalized over its decorating sites rest in the entangled state composed of two intrinsic antiferromagnetic states $c_{k1,\uparrow}^{\dagger}c_{k2,\downarrow}^{\dagger}|0\rangle$, $c_{k1,\downarrow}^{\dagger}c_{k2,\uparrow}^{\dagger}|0\rangle$, and two nonmagnetic ionic states $c_{k1,\uparrow}^{\dagger}c_{k1,\downarrow}^{\dagger}|0\rangle$ and $c_{k2,\uparrow}^{\dagger}c_{k2,\downarrow}^{\dagger}|0\rangle$. The quantum entanglement of those four microstates arises from a virtual hopping process of the itinerant electrons, which is diagrammatically illustrated in Fig. 2. The respective probability distribution of the four entangled microstates is displayed in Fig. 3 as a function of a relative strength of the hopping term.

Let us make a few comments on an origin of the remarkable four-sublattice quantum antiferromagnet emerging in $|AF\rangle$. The hopping process of both itinerant electrons energetically favors their antiparallel spin alignment and this antiferromagnetic correlation is subsequently mediated through

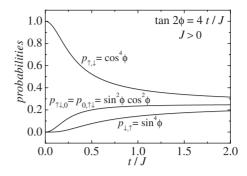


FIG. 3. The probability distribution for the four entangled microstates as a function of the ratio between the hopping term t and the Ising exchange constant J.

the Ising-type exchange interaction J also on their two nearest-neighbor Ising spins (hence, the antiferromagnetic character of the effective interaction R < 0 between the Ising spins). If a relative strength of the hopping term is sufficiently weak, the Ising spins prefer the ferromagnetic alignment with respect to their nearest-neighbor mobile electrons as it can be clearly seen from the occurrence probability of the majority microstate $c_{k1,\uparrow}^{\dagger}c_{k2,\downarrow}^{\prime}|0\rangle$ that converges to $p_{\uparrow,\downarrow} \rightarrow 1$ in the limit $t/J \rightarrow 0$. It is nevertheless worth mentioning that the occurrence probabilities of three minority microstates monotonically increase upon strengthening the hopping term at the expense of the occurrence probability of the majority microstate until they asymptotically reach the same value $p_{\uparrow,\downarrow}=p_{\downarrow,\uparrow}=p_{\uparrow\downarrow,0}=p_{\downarrow\uparrow,0}\rightarrow 1/4$ in the limit $t/J\rightarrow\infty$.

B. Finite-temperature phase diagram

Next, let us examine critical phenomena associated with finite-temperature phase transitions of the spontaneously long-range ordered phase $|AF\rangle$. It is worthwhile to recall that the critical temperature can easily be obtained by solving numerically the critical conditions derived in the foregoing section. The finite-temperature phase diagram in the form of the critical temperature versus the kinetic term dependence is shown in Fig. 4 for the interacting spin-electron system on doubly decorated square and honeycomb lattices. It is quite

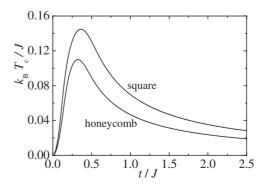


FIG. 4. The dimensionless critical temperature as a function of the relative strength of the hopping term for the interacting spinelectron system on the doubly decorated square and honeycomb lattices.

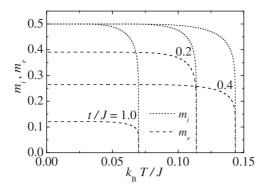


FIG. 5. Thermal dependences of both sublattice staggered magnetizations for the interacting spin-electron system on the doubly decorated square lattice at three different values of a relative strength of the hopping term t/J=0.2, 0.4, and 1.0.

obvious from this figure that the interacting spin-electron system on any loose-packed doubly decorated 2D lattice exhibits the same general trends in the relevant dependences of the critical temperature. The critical temperature initially exhibits a relatively rapid increase from zero temperature with increasing the ratio between the hopping term t and the exchange constant J until it achieves its maximum value. The critical temperature then gradually decreases upon further increase in a relative strength of the kinetic energy before it again tends to zero temperature in the other particular limit $t/J \rightarrow \infty$. In the limit $t/J \rightarrow 0$, the observed zero critical temperature can be attributed to a localization of the itinerant electrons at particular decorating sites. In fact, there does not exist any other interaction between the itinerant electrons within the tight-binding model described by Hamiltonian (1) except the effective interaction originating from their virtual hopping process. If the hopping process of the itinerant electrons is ignored, the interacting spin-electron system immediately splits into independent fragments consisting of one central Ising spin merely coupled to the q localized electrons residing its nearest-neighbor decorating sites. It is worthy of notice, moreover, that the thermally assisted hopping cannot restore a spontaneous long-range order at any finite temperature in the limit $t/J \rightarrow 0$ since all available electronic configurations are thermally excited with the same probability in an absence of the interaction between the mobile electrons. In the other particular limit $t/J \rightarrow \infty$, the zero critical temperature results from the same probabilities of the four entangled microstates of $|AF\rangle$ as it has been already discussed by the ground-state analysis. Owing to this fact, the decorating sites occupied by the mobile electrons have nonmagnetic character, which is in accordance with a disappearance of the effective interaction R=0 between the localized Ising spins that occurs in the particular limit $t/J \rightarrow \infty$.

C. Order parameter

Temperature variations in both sublattice staggered magnetizations m_i and m_e are depicted in Fig. 5 for three different values of a relative strength of the kinetic energy. The most obvious difference between the sublattice staggered magnetizations m_i and m_e pertinent to the Ising spins and itinerant

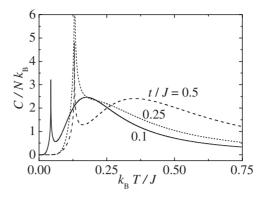


FIG. 6. Temperature variations in the specific heat for the interacting spin-electron system on the doubly decorated square lattice at three different values of a relative strength of the hopping term t/J=0.1, 0.25, and 0.5.

electrons, respectively, lies in the quantum reduction in the latter staggered magnetization. The greater a relative strength of the hopping term is, the greater quantum reduction in the staggered magnetization m_e can be observed in Fig. 5 in concordance with the relevant ground-state prediction of the lowest-energy eigenstate [Eq. (16)], as well as the zero-temperature limit of the expression in Eq. (15) both yielding

$$m_e(T=0) = \frac{1}{2} \frac{J}{\sqrt{J^2 + (4t)^2}}.$$
 (18)

On the other hand, the sublattice staggered magnetization m_i pertinent to the Ising spins always starts from its maximum possible value that implies a perfect Néel long-range order of the localized Ising spins. For completeness, it is also worthy of notice that both sublattice staggered magnetizations tend to zero in a vicinity of the critical temperature with the critical exponent $\beta = 1/8$ from the standard Ising universality class.

D. Specific heat

Finally, thermal dependences of the specific heat are plotted in Fig. 6 for the interacting spin-electron system on the doubly decorated square lattice at three different relative strengths of the kinetic term t/J=0.1, 0.25, and 0.5. It is quite evident that the investigated model system exhibits the familiar logarithmic singularity at critical temperature of the order-disorder transition, which provides another independent confirmation of the critical behavior from the standard Ising universality class.

In addition to the logarithmic divergence observed in a close vicinity of the critical point, the specific heat also displays a round Schottky-type maximum in the high-temperature tail of the specific-heat curve. This maximum is well separated from the logarithmic singularity at relatively weak hopping terms (see solid line for t/J=0.1) while it becomes superimposed on a logarithmic divergence at moderate strengths of the kinetic term (see dotted line for t/J=0.25). Last but not least, the round high-temperature maximum again separates from the logarithmic singularity upon further increase in a relative strength of the hopping

term. In fact, the round maximum shifts toward higher temperatures and becomes broader as the value of t/J is furthermore increased (see dashed line for t/J=0.5).

IV. CONCLUDING REMARKS

In this paper, the hybrid lattice-statistical model of the interacting spin-electron system on doubly decorated 2D lattices has exactly been solved by the use of generalized decoration-iteration transformation under the constraint of a half filling of each couple of the decorating sites. It has been shown that the ground state of the investigated model system defined on any doubly decorated loose-packed 2D lattice represents an interesting four-sublattice quantum antiferromagnetic phase. It is worth noticing, moreover, that this foursublattice quantum antiferromagnet exhibits a remarkable combination of the spontaneous long-range order manifested through a nontrivial criticality at nonzero temperatures with obvious macroscopic features of quantum origin such as the quantum reduction in the staggered magnetization pertinent to the itinerant electrons. To the best of our knowledge, the model under investigation thus represents a rather rare example of the exactly solved model with such an intriguing combination of otherwise hardly compatible properties.

To compare with, it is worthwhile to remark that the interacting spin-electron system at a quarter filling (i.e., with one mobile electron confined at each couple of decorating sites) merely exhibits a semiclassical ferromagnetic or ferrimagnetic spontaneous long-range order depending on whether the ferromagnetic or antiferromagnetic interaction between the localized Ising spins and itinerant electrons is assumed.⁵⁵ This fact clearly demonstrates that an existence of the four-sublattice quantum antiferromagnetic phase in the interacting spin-electron system at a half filling closely relates to a collective behavior of mobile electrons even if there does not exist any direct interaction between them within our tight-binding model. In addition, there are also other fundamental differences between both these models. The critical temperature, which reflects a robustness of the spontaneous long-range order with respect to thermal fluctuations, monotonically increases with increasing a relative strength of the kinetic term in the interacting spin-electron system at a quarter filling. This means that a strengthening of the kinetic term supports a semiclassical spontaneous longrange order of this interacting spin-electron system. On the other hand, the critical temperature of the interacting spinelectron system at a half filling exhibits a nonmonotonous dependence with a pronounced maximum at some moderate strength of the kinetic term, which indicates that the hopping process supports a robustness of the spontaneous long-range ordering against thermal fluctuations just for relatively weak kinetic terms.

Besides the purely academic interest in searching exactly solvable quantum spin models, the considered model system has also been suggested in order to bring insight into a magnetism of hybrid systems consisting of both localized spins as well as mobile electrons. Among the most famous magnetic materials, which obey this specific requirement, one could mention the magnetic metal $SrCo_6O_{11}$ (Refs. 56–59) or series of polymeric coordination compounds the $[\operatorname{Ru}_2(\operatorname{OOC} t\operatorname{Bu})_4]_3[M(\operatorname{CN})_6]$ [M=Fe (Refs. 60–62) and Cr (Refs. 62 and 63)]. In the latter family of magnetic materials, one and three unpaired electrons of the trivalent metal ions such as Fe^{3+} (S=1/2) and Cr^{3+} (S=3/2) are localized at the corners of a simple square lattice, whereas three unpaired electrons are delocalized over the mixed-valent dimeric unit Ru₂⁵⁺ residing each bond of the square lattice.⁶⁴ In this respect, the magnetic structure of this series of coordination compounds closely resembles the one of the suggested model system even though the electronic structure of the mixed-valent dimeric unit Ru25+ would surely require more complex Hamiltonian in order to describe the doubleexchange mechanism in the mixed-valent Ru_2^{5+} dimeric unit. In this direction will continue our further work.

ACKNOWLEDGMENTS

This work was supported by the Slovak Research and Development Agency under Contract No. LPP-0107-06. The financial support provided by the VEGA under Grant No. 1/2009/05 and VVGS under Grant No. 2/09-10 is also gratefully acknowledged.

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